

Excellent Integrated System Limited

Stocking Distributor

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<u>Vishay Semiconductor/Diodes Division</u> <u>VCUT03B1-DD1-G-08</u>

For any questions, you can email us directly: sales@integrated-circuit.com

Distributor of Vishay Semiconductor/Diodes Division: Excellent Integrated System Limite

Datasheet of VCUT03B1-DD1-G-08 - TVS DIODE 3.5VWM 11.5VC 2LLP

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www.vishay.com

VCUT03B1-DD1

RoHS

COMPLIANT

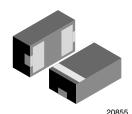
HALOGEN FREE

GREEN

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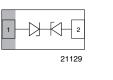
Bidirectional Symmetrical (BiSy) Single Line ESD-Protection Diode in LLP1006-2M





FEATURES

- Ultra compact LLP1006-2M package
- Low package height < 0.4 mm
- 1-line ESD-protection
- Working range ± 3.5 V
- Low leakage current < 0.1 μA
- Low load capacitance C_D = 12.5 pF
- ESD-protection acc. IEC 61000-4-2 ± 18 kV contact discharge
 - ± 20 kV air discharge
- Soldering can be checked by standard vision inspection. No X-ray necessary
- Pin plating NiPdAu (e4) no whisker growth
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912





Bar = pin 1 marking X = date code

Y = type code (see table below)

ORDERING INFORMATION				
DEVICE NAME	DEVICE NAME ORDERING CODE		MINIMUM ORDER QUANTITY	
VCUT03B1-DD1	VCUT03B1-DD1-G-08	8000	8000	

PACKAGE DATA						
DEVICE NAME	PACKAGE NAME	TYPE CODE	WEIGHT	MOLDING COMPOUND FLAMMABILITY RATING	MOISTURE SENSITIVITY LEVEL	SOLDERING CONDITIONS
VCUT03B1-DD1	LLP1006-2M	N	0.72 mg	UL 94 V-0	MSL level 1 (according J-STD-020)	260 °C/10 s at terminals

ABSOLUTE MAXIMUM RATINGS VCUT03B1-DD1					
PARAMETER	TEST CONDITIONS	SYMBOL VALUE		UNIT	
Peak pulse current	Acc. IEC 61000-4-5; $t_p = 8/20 \mu s$; single shot	I _{PPM}	3.5	А	
Peak pulse power	Pin 1 to pin 2 acc. IEC 61000-4-5; $t_p = 8/20 \mu s$; single shot	P _{PP}	40	W	
ESD immunity	Contact discharge acc. IEC61000-4-2; 10 pulses	V	± 18	kV	
	Air discharge acc. IEC61000-4-2; 10 pulses	V_{ESD}	± 20		
Operating temperature	Junction temperature	TJ	-40 to +125	°C	
Storage temperature		T _{STG}	-55 to +150	°C	

PATENT(S): www.vishay.com/patents

This Vishay product is protected by one or more United States and International patents.

Rev. 1.8, 08-Jun-16 Document Number: 81148 For technical questions, contact: ESDprotection@vishay.com

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CUT THE SPIKES WITH VCUT03B1-DD1

The VCUT03B1-DD1 is a bidirectional and symmetrical (BiSy) ESD-protection device which clamps positive and negative overvoltage transients to ground. Connected between the signal or data line and the ground the VCUT03B1-DD1 offers a high isolation (low leakage current, low capacitance) within the specified working range. Due to the short leads and small package size of the tiny LLP1006-2M package the line inductance is very low, so that fast transients like an ESD-strike can be clamped with minimal over- or undershoots.

ELECTRICAL CHARACTERISTICS VCUT03B1-DD1 (T _{amb} = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITIONS/REMARKS	SYMBOL	MIN.	TYP.	MAX.	UNIT	
Protection paths	Number of lines which can be protected	N _{channel}	-	-	1	lines	
Reverse stand-off voltage	Max. reverse working voltage	V_{RWM}	-	-	3.5	V	
Reverse voltage	at I _R = 0.1 μA	V_R	3.5	-	-	V	
Reverse current	at V = 3.5	I _R	-		0.1	μΑ	
Reverse breakdown voltage	at I =1 mA	V_{BR}	5.8	6.7	7.5	V	
Reverse clamping voltage	at I _{PP} = 1 A	V _C	-	7.8	9	V	
	at I _{PP} = I _{PPM} = 3.5 A	V _C	-	9.5	11.5	V	
Capacitance	at V = 0 V; f = 1 MHz	C_D	-	12.5	15	pF	
	at V = 2.5 V; f = 1 MHz	C _D	-	11.5	-	pF	

TYPICAL CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

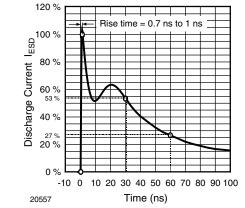


Fig. 1 - ESD Discharge Current Wave Form acc. IEC 61000-4-2 (330 Ω/150 pF)

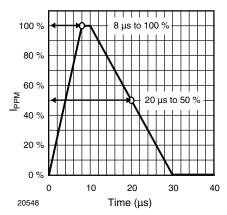


Fig. 2 - 8/20 µs Peak Pulse Current Wave Form acc. IEC 61000-4-5

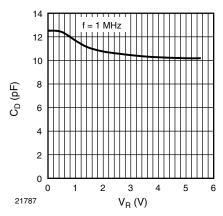


Fig. 3 - Typical Capacitance C_D vs. Reverse Voltage V_R

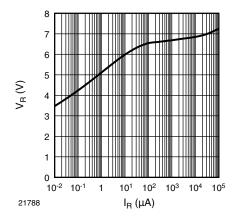


Fig. 4 - Typical Forward Current I_F vs. Forward Voltage V_F

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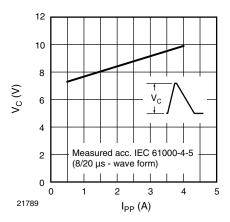


Fig. 5 - Typical Reverse Voltage V_{R} vs. Reverse Current I_{R}

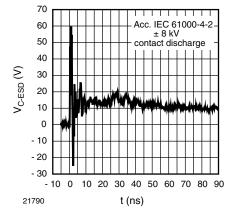


Fig. 6 - Typical Peak Clamping Voltage $V_{\mathbb{C}}$ vs. Peak Pulse Current I_{PP}

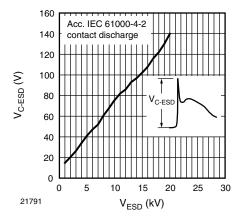


Fig. 7 - Typical Clamping Performance at + 8 kV Contact Discharge (acc. IEC 61000-4-2)

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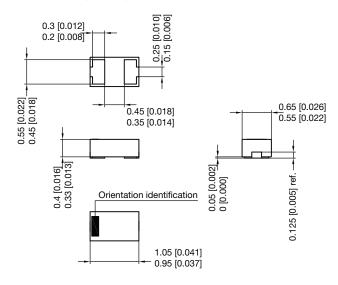
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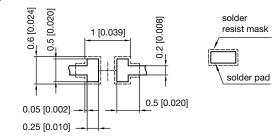
VCUT03B1-DD1

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PACKAGE DIMENSIONS in millimeters (Inches): LLP1006-2M

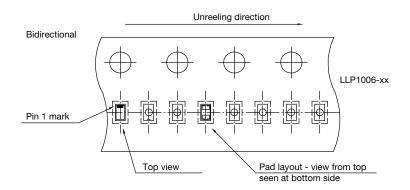


Foot print recommendation:



Pad Design Patented: (P)US 9.018.537 B2)

Document no.: S8-V-3906.04-005 (4) Rev. 7 - Date: 11.May 2016 20812





Distributor of Vishay Semiconductor/Diodes Division: Excellent Integrated System Limite Datasheet of VCUT03B1-DD1-G-08 - TVS DIODE 3.5VWM 11.5VC 2LLP

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